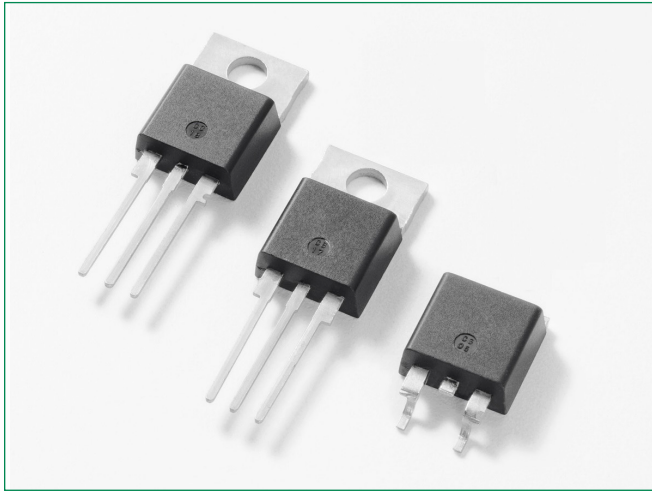


QVxx25xHx Series

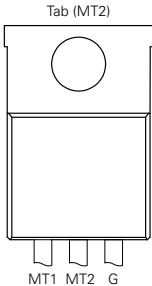
25 A High Temperature Alternistor TRIACs

HF RoHS L Package: E71639

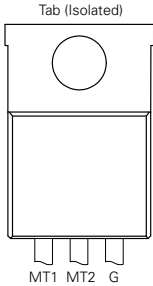


Pinout Diagram

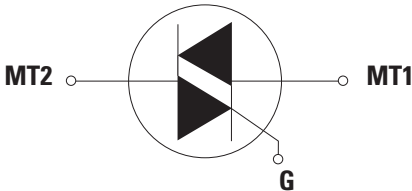
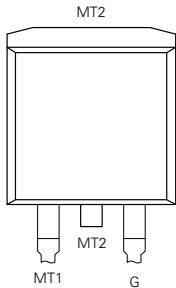
TO-220AB (R-Package)



TO-220AB (L-Package)



TO-263AB



MT1: Main Terminal 1; **MT2:** Main Terminal 2; **G:** Gate

Description

This 25 A high temperature Alternistor TRIAC, offered in TO-220AB, TO-220 isolated, and TO-263 packages, has 150°C maximum junction temperature (T_j) and 250 A I_{TSM} (60 Hz). This series enables easier thermal management and higher surge handling capability in AC power control applications such as heater control, motor speed control, lighting controls, and static switching relays. Alternistor TRIAC operates in quadrants I, II, and III, and offers high performance in applications requiring high commutation capability.

Features & Benefits

- High T_j of 150°C
- Voltage capability of 800 V
- Surge capability of 250 A at 60 Hz half cycle
- Mechanically and thermally robust TO-220 clip-attach assembly
- High dv/dt up to 2000 V/ μ s
- Internally-isolated TO-220 package
- Halogen-free and RoHS-compliant
- Recognized to UL 1557 as an Electrically Isolated Semiconductor Device

Applications

TRIAC is an excellent AC switch in applications such as heating, lighting, and motor speed controls.

Typical applications are:

- Heater control such as coffee brewer, tankless water heater, and infrared heater
- AC solid-state relays
- Light dimmers including incandescent and LED lighting
- Motor speed control in kitchen appliances, power tools, home/brow/white goods and light industrial applications such as compressor motor control

Alternistor TRIAC is used with high inductive loads requiring high commutation capability. Internally isolated packages offer better heat sinking with higher isolation voltage.

Product Summary

Characteristic	Value	Unit
$I_{T(RMS)}$	25	A
V_{DRM}/V_{RRM}	600 or 800	V
$I_{GT(Q1)}$	35 or 50	mA

QVxx25xHx Series

25 A High Temperature Alternistor TRIACs

Maximum Ratings — Alternistor TRIAC (3 Quadrants)

Symbol	Characteristic	Conditions	Value	Unit
$I_{T(RMS)}$	RMS On-State Current (Full Sine Wave)	QVxx25LHy $T_C = 100^\circ\text{C}$	25	A
		QVxx25RHy / QVxx25NHx $T_C = 125^\circ\text{C}$		
I_{TSM}	Non-Repetitive Surge Peak On-State Current (Single Half Cycle, T_J Initial = 25°C)	$f = 50\text{ Hz}$, $t = 20\text{ ms}$	208	A
		$f = 60\text{ Hz}$, $t = 16.7\text{ ms}$	250	
I^2t	I^2t Value For Fusing	$t_p = 8.3\text{ ms}$	260	A^2s
di/dt	Critical Rate Of Rise Of On-State Current	$f = 60\text{ Hz}$, $T_J = 150^\circ\text{C}$	100	$\text{A}/\mu\text{s}$
I_{GTM}	Peak Gate Trigger Current	$t_p \leq 10\text{ }\mu\text{s}$, $I_{GT} \leq I_{GTM}$, $T_J = 150^\circ\text{C}$	4	A
$P_{G(AV)}$	Average Gate Power Dissipation	$T_J = 150^\circ\text{C}$	1	W
T_{stg}	Storage Temperature Range	–	-40 to 150	$^\circ\text{C}$
T_{VJ}	Operating Junction Temperature Range	–	-40 to 150	$^\circ\text{C}$
V_{DSM}/V_{RSM}	Non Repetitive Surge Peak Off-State Voltage	pulse width = $100\text{ }\mu\text{s}$; $V_{DRM}/V_{RRM} = 600\text{ V}$	700	V
		pulse width = $100\text{ }\mu\text{s}$; $V_{DRM}/V_{RRM} = 800\text{ V}$	1000	

xx = voltage/10; y = sensitivity

Thermal Characteristics

Symbol	Characteristic	Value	Unit
$R_{th(JC)}$	Thermal Resistance, Junction-To-Case (AC)	QVxx25RHy/ QVxx25NHx	0.90
		QVxx25LHy	1.8

Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified) — Alternistor TRIAC (3 Quadrants)

Symbol	Description	Conditions		QVxx25xH4			QVxx25xH5			Unit
				Min	Typ	Max	Min	Typ	Max	
I _{GT}	DC Gate Trigger Current	V _D = 12 V R _L = 60 Ω	I – II – III	–	–	35	–	–	50	mA
V _{GT}	DC Gate Trigger Voltage		I – II – III	–	–	1.3	–	–	1.3	V
V _{GD}	Gate Non-trigger Voltage	V _D = V _{DRM} R _L = 3.3 kΩ T _J = 150°C	I – II – III	0.15	–	–	0.15	–	–	V
I _H	Holding Current	I _T = 400mA		–	–	50	–	–	75	mA
dv/dt	Critical Rate-of-rise of Off-stage Voltage	V _D = V _{DRM} Gate Open T _J = 150°C		500	–	–	750	–	–	V/μs
		V _D = 2/3 V _{DRM} Gate Open T _J = 150°C		1000	–	–	2000	–	–	
(dv/dt) _c	-	(di/dt) _c = 13.3 A/ms T _J = 150°C		25	–	–	30	–	–	V/μs
t _{gt}	Turn-on Time	I _G = 2 x I _{GT} P _W = 15 μs I _T = 35.4 A(pk)	I	–	3	–	–	3	–	μs
			II	–	5	–	–	5	–	
			III	–	13	–	–	15	–	

xx = voltage/10;

x = sensitivity

Static Characteristics

Symbol	Description	Conditions	Maximum Value	Unit
V_{TM}	Peak On-state Voltage	$I_T = 35.4\text{ A}$ $t_p = 380\text{ }\mu\text{s}$	1.50	V
I_{DRM}/I_{RRM}	Off-state Current, Peak Repetitive	$V_D = V_{DRM}/V_{RRM}$ $T_J = 25^\circ\text{C}$	5	μA
		$V_D = V_{DRM}/V_{RRM}$ $T_J = 150^\circ\text{C}$	4	mA
V_{T0}	Threshold Voltage	$T_J = 150^\circ\text{C}$	0.85	V
R_D	Dynamic Resistance	$T_J = 150^\circ\text{C}$	17	m Ω

QVxx25xHx Series

25 A High Temperature Alternistor TRIACs

Performance Curves

Figure 1: Definition of Quadrants

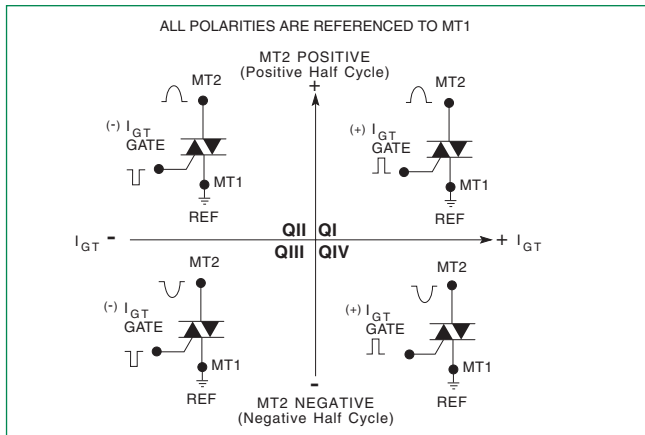


Figure 2: Normalized DC Gate Trigger Current for All Quadrants vs. Junction Temperature

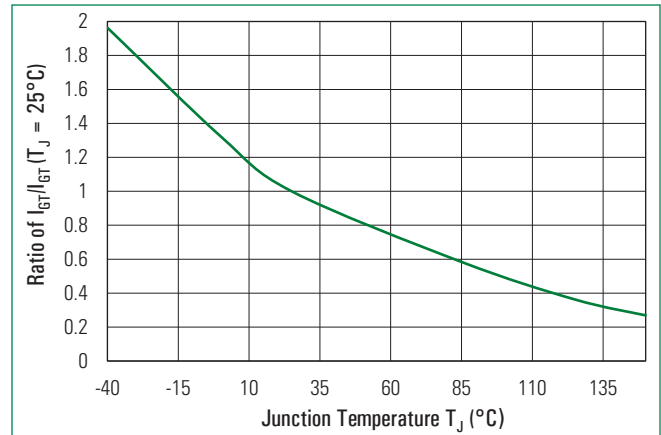


Figure 3: Normalized DC Holding Current vs. Junction Temperature

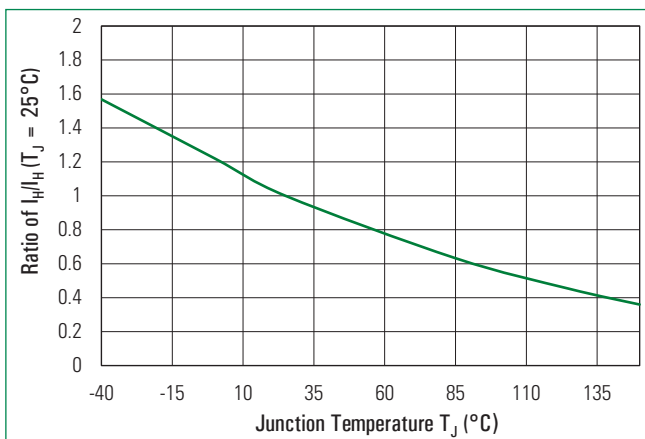


Figure 4: Normalized DC Gate Trigger Voltage for All Quadrants vs. Junction Temperature

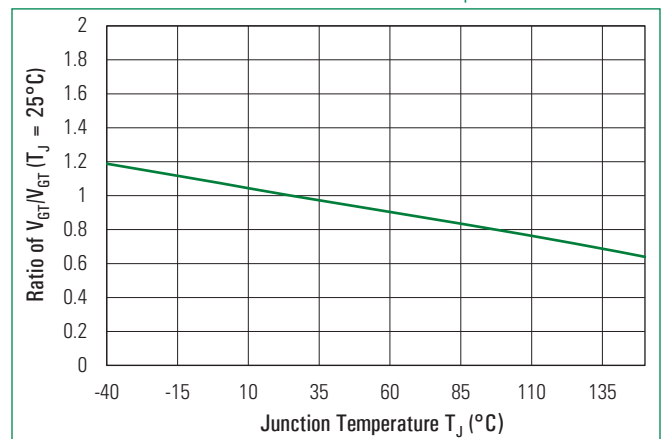


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

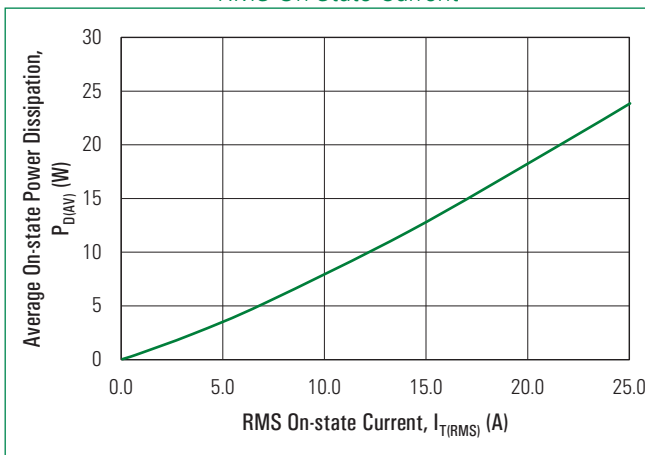
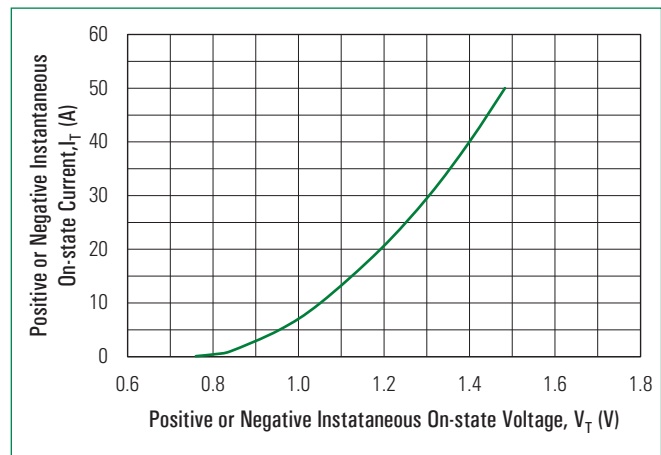


Figure 6: On-State Current vs. On-State Voltage (Typical)



QVxx25xHx Series

25 A High Temperature Alternistor TRIACs

Figure 7: Maximum Allowable Case Temperature vs. RMS On-State Current

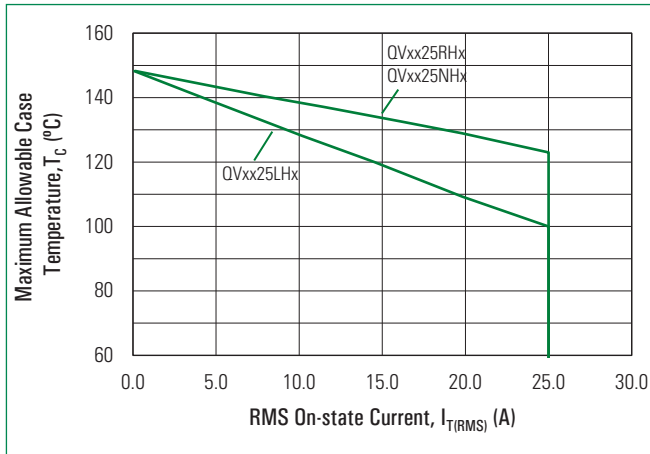
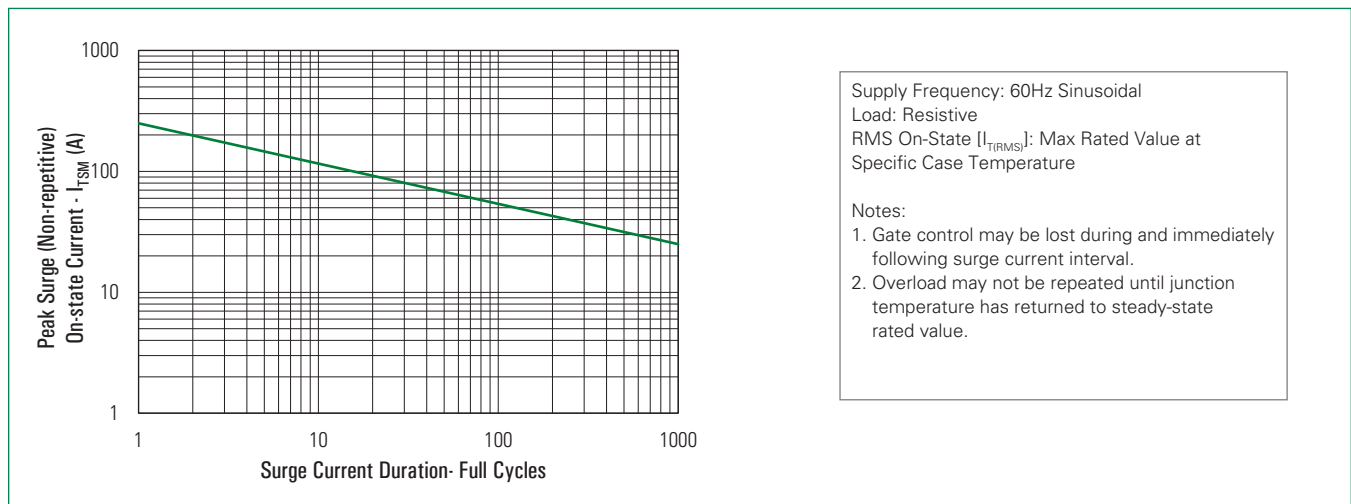
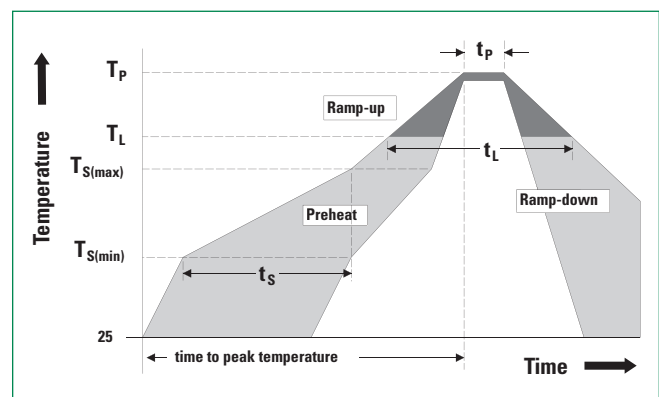


Figure 8: Surge Peak On-State Current vs. Number of Cycles



Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 seconds
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/s Max.
$T_{S(Max)}$ to T_L - Ramp-up Rate		5°C/s Max.
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Time (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 °C (± 5)
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/s Max.
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		280°C



QVxx25xHx Series

25 A High Temperature Alternistor TRIACs

Physical Specifications

Terminal Finish	100% Matte Tin-plated
Body Material	UL Recognized compound meeting flammability rating 94V-0
Terminal Material	Copper Alloy

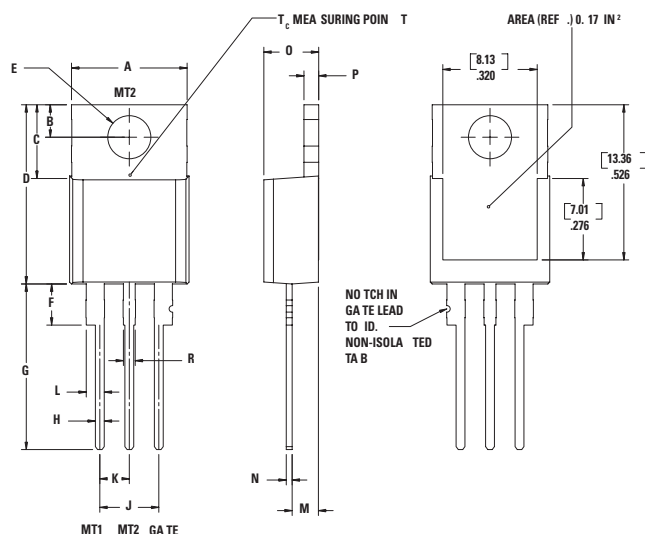
Design Considerations

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 150°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 1000 cycles; -55°C to +150°C; 15-min dwell time
Temperature/Humidity	EIA/ JEDEC, JESD22-A101, 1008 hours; 160 V - DC: 85°C; 85% rel humidity
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E
Moisture Sensitivity Level	Level 1, JEDEC-J-STD-020
UHAFT	JESD22A-118, 96 hrs, 130°C/ 85% RH
IOL	MIL-STD-750 Method 1037

Dimensions - TO-220AB (R-Package) - Non-Isolated Mounting Tab Common with Center Lead



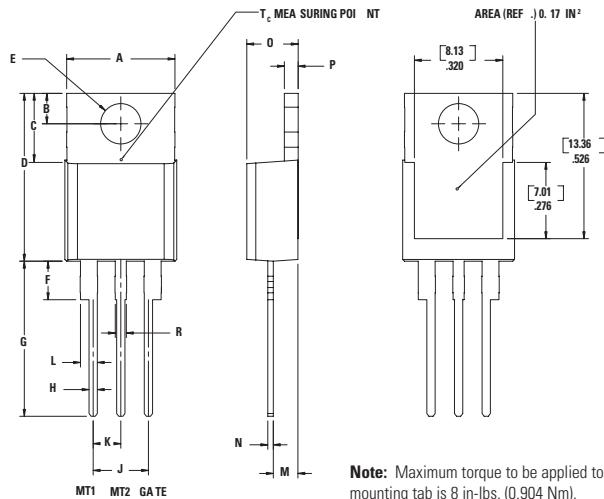
Note: Maximum torque to be applied to mounting tab is 8 in-lbs. (0.904 Nm).

Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.380	0.420	9.65	10.67
B	0.105	0.115	2.66	2.92
C	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
H	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
M	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
O	0.178	0.188	4.52	4.78
P	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

QVxx25xHx Series

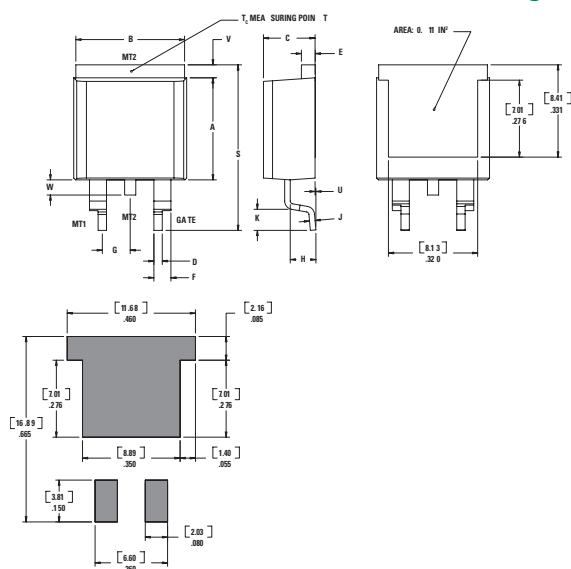
25 A High Temperature Alternistor TRIACs

Dimensions - TO-220AB (L-Package) - Isolated Mounting Tab



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.380	0.420	9.65	10.67
B	0.105	0.115	2.67	2.92
C	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.60
H	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
M	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
O	0.178	0.188	4.52	4.78
P	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

Dimensions - TO-263AB (N-Package) - D2Pak Surface Mount



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.360	0.370	9.14	9.40
B	0.380	0.420	9.65	10.67
C	0.178	0.188	4.52	4.78
D	0.025	0.035	0.64	0.89
E	0.045	0.060	1.14	1.52
F	0.060	0.075	1.52	1.91
G	0.095	0.105	2.41	2.67
H	0.092	0.102	2.34	2.59
J	0.018	0.024	0.46	0.61
K	0.090	0.110	2.29	2.79
S	0.590	0.625	14.99	15.88
V	0.035	0.045	0.89	1.14
U	0.002	0.010	0.05	0.25
W	0.040	0.070	1.02	1.78

Product Selector

Part Number	Voltage	Voltage	Gate Sensitivity Quadrants I – II – III	Type	Package
	600V	800V			
QVxx25LH4	-	X	35 mA	Alternistor TRIAC	TO-220L
QVxx25RH4	-	X	35 mA	Alternistor TRIAC	TO-220R
QVxx25NH4	-	X	35 mA	Alternistor TRIAC	TO-263 D ² -PAK
QVxx25LH5	X	X	50 mA	Alternistor TRIAC	TO-220L
QVxx25RH5	X	X	50 mA	Alternistor TRIAC	TO-220R
QVxx25NH5	X	X	50 mA	Alternistor TRIAC	TO-263 D ² -PAK

